



R U N A U

Jiangsu Runau Electronics Manufacturing Co.,Ltd

ZP1350-Rectifier Diode

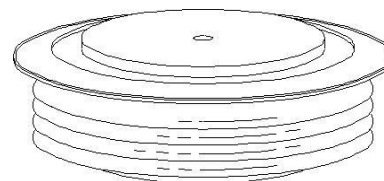
3600~4500 V_{RRM}

GENERAL PURPOSE HIGH POWER STANDARD RECTIFIER

Features:

- . All Diffused Structure
- . High Surge rating
- . Blocking capability up to 4500 volts
- . Ceramic Housing Hermetic Package
- . Pressure Assembled Device

ZT65cT



ELECTRICAL CHARACTERISTICS AND RATINGS

Reverse Blocking

Device Type	V _{RRM} (1)	V _{RSM} (1)
ZP1350-36	3600	3800
ZP1350-38	3800	4000
ZP1350-40	4000	4200
ZP1350-42	4200	4400
ZP1350-45	4500	4700

V_{RRM} = Repetitive peak reverse voltage

V_{RSM} = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage	I _{RRM}	5 mA 70 mA (3)
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Notes:

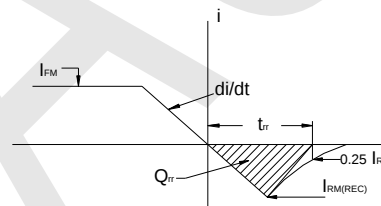
All ratings are specified for T_j=25 °C unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range 0 to +150 °C.

(2) 10 msec. max. pulse width

(3) Maximum value for T_j = 150 °C.

(4) See parameter definition below:



REVERSE RECOVERY CHARACTERIST

Conducting - on state

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average value of on-state current	I _{F(AV)}		1350		A	Sinewave, 180°, T _c =100°C
RMS value of on-state current	I _{FRMS}		2119		A	Nominal value
Peak one cycle surge (non repetitive) current	I _{FSM}		20250		A	10 msec (50Hz), sinusoidal wave-shape, 180° conduction, T _j = 150 °C
I square t	I ² t		2×10 ⁶		A ² s	10 msec
Peak on-state voltage	V _{FM}		1.8		V	I _{FM} = 3000A;T _j =25°C
Threshold voltage	V _{FO}		0.95		V	T _j =150°C,I=0.5π I _{F(AV)} to 1.5π I _{F(AV)}
Threshold voltage, Low-level	r _F		0.22		mΩ	T _j =150°C,I=0.5π I _{F(AV)} to 1.5π I _{F(AV)}
Reverse Recovery Current (4)	I _{RM(REC)}				A	I _{FM} = 500 A; di/dt = -10 A/s;T _j max
Reverse Recovery Charge (4)	Q _{rr}			5000	μC	I _{FM} = 500 A; di/dt = -10 A/s;T _j max
Reverse Recovery Time (4)	t _{rr}				μs	I _{FM} = 500 A; di/dt = -10 A/s;T _j max

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T_j	-40	+150		$^{\circ}\text{C}$	
Storage temperature	T_{stg}	-40	+150		$^{\circ}\text{C}$	
Thermal resistance - junction to case	$R_{\Theta(j-c)}$		0.015		$^{\circ}\text{C/W}$	Double sided cooled
Thermal resistance - case to heatsink	$R_{\Theta(c-s)}$		0.0045		$^{\circ}\text{C/W}$	Double sided cooled
Mounting force	P	27	33	30	kN	
Weight	W			0.72	kg.	

* Mounting surfaces smooth, flat and greaseless

CASE OUTLINE AND DIMENSIONS

